

Basic Electronics ( EC21101 )

End Semester Examination

Spring 2010

Full marks : 75

Answer all questions. The marks for each question is indicated to the right.

1. (a) Determine the built-in potential barrier  $V_{bi}$  in a Si pn junction with an intrinsic carrier concentration  $n_i = 1.5 \times 10^{10} \text{ cm}^{-3}$  for (i)  $N_d = N_a = 10^{16} \text{ cm}^{-3}$ ; (ii)  $N_d = 10^{18} \text{ cm}^{-3}$ ,  $N_a = 10^{16} \text{ cm}^{-3}$ ; and (iii)  $N_d = N_a = 10^{18} \text{ cm}^{-3}$ .
- (b) Assume each diode in the circuit shown in Fig. 1 to have a cut-in voltage of  $V_\gamma = 0.65\text{V}$ . (i) For an input voltage of  $V_i = 5\text{V}$ , determine the value of  $R_1$  required such that the current  $I_{D1}$  is one half of the value of the current  $I_{D2}$ . What are the values of  $I_{D1}$  and  $I_{D2}$ ? (iii) If  $V_i = 8\text{V}$  and  $R_1 = 2\text{k}\Omega$ , determine the currents  $I_{D1}$  and  $I_{D2}$ .

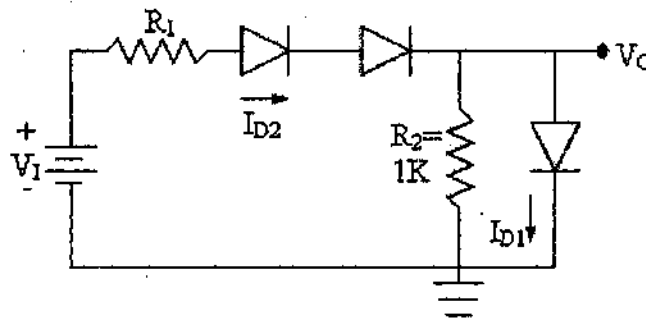


Fig. 1

[ 3+7=10 ]

2. Find the value of  $R_1$ ,  $R_2$ ,  $R_s$  and  $R_D$  in the circuit shown in Fig. 2 for  $I_{DQ} = 0.25\text{mA}$  and  $V_{DSQ} = 4\text{V}$  with the voltage across  $R_s$  at  $1\text{V}$ . Assume that the current through  $R_1$  is  $20\mu\text{A}$ . The NMOS parameters are as follows :  $k'_n = 80\mu\text{A}/\text{V}^2$ ,  $V_{TN} = 1.2\text{V}$  and  $W/L = 4$ .

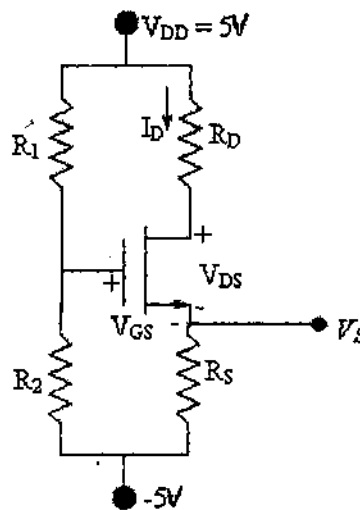


Fig. 2

[10]

3. Assume  $V_\gamma = 0.7V$  for each diode. Plot  $V_o$  versus  $V_i$  for  $-10V < V_i < +10V$  for the circuit shown in Fig. 3.

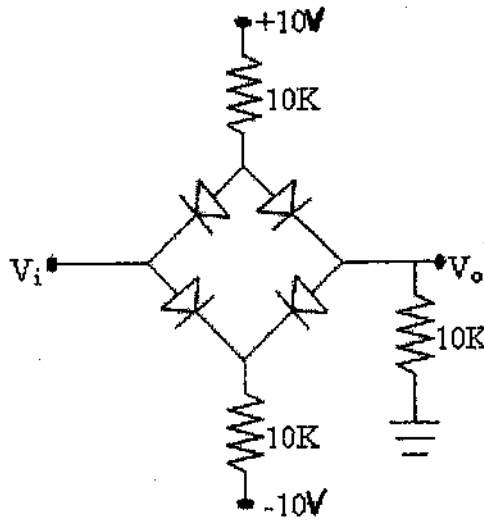


Fig. 3

[8]

4. Calculate the small signal voltage gain of the common source amplifier shown in Fig. 4, with  $g_m = 1 mA/V$ ,  $r_o = 50k\Omega$  and  $R_D = 10k\Omega$ . Assume  $R_{S1} = 2k\Omega$  and  $R_1 \parallel R_2 = 50k\Omega$ .

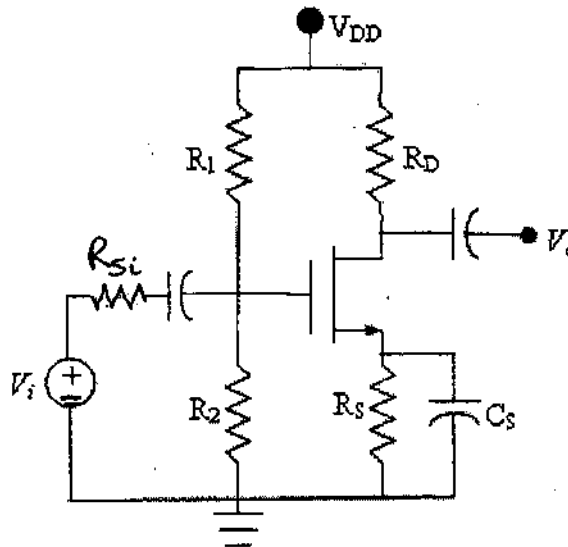


Fig. 4

[7]

5. (a) Consider the circuit shown in Fig. 5. The transistor parameters are  $\beta = 100$  with the Early voltage  $V_A = 100$  V. Determine the input resistance  $R_i$ , the voltage gain  $A_v = v_o/v_s$  and the current gain  $A_i = i_o/i_s$ .

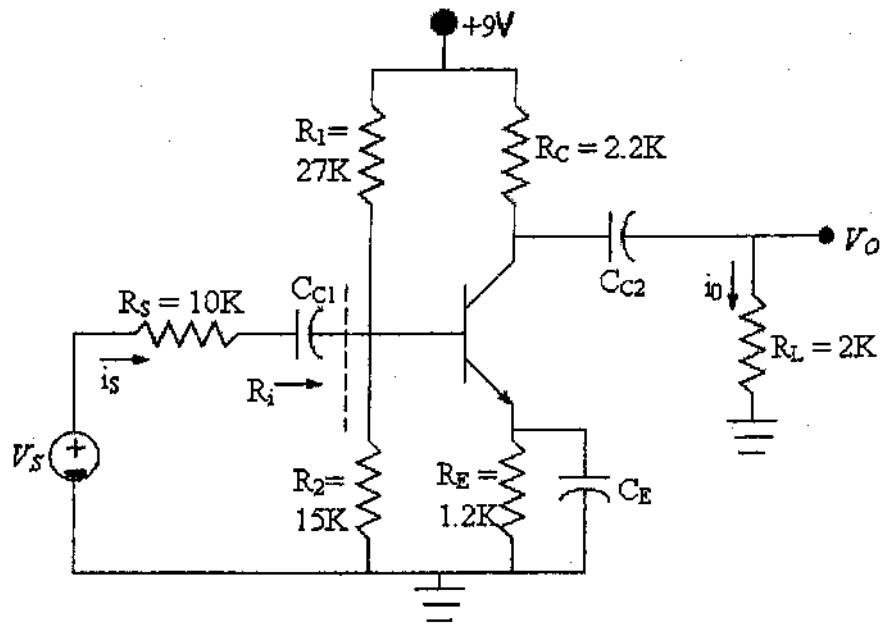


Fig. 5

[12]

- (b) Assume that  $\beta = 100$ ,  $R_1 = 10$  k $\Omega$  and  $R_2 = 50$  k $\Omega$ , with the Early voltage  $V_A = \infty$  for the circuit shown in Fig. 6. (i) Determine the small signal voltage gain. (ii) Also find the range of voltage gain if the resistance values  $R_E$  and  $R_C$  vary by  $\pm 5\%$ .

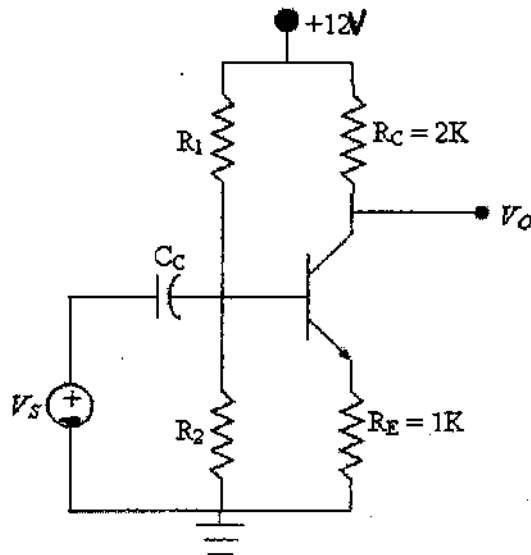


Fig. 6

[12 + 6 = 18]

6.

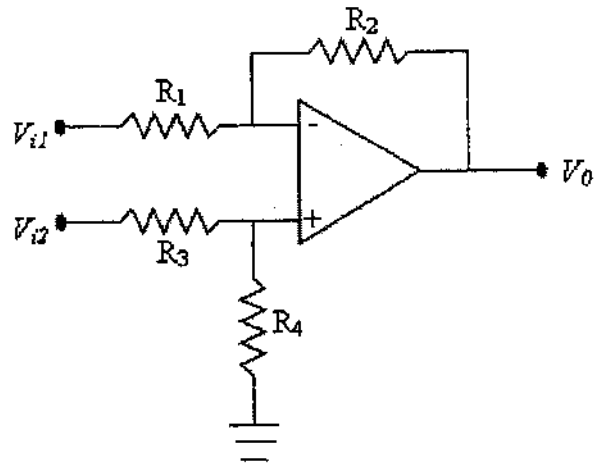


Fig. 7

In the differential amplifier shown in Fig. 7,  $R_1 = R_3 = 10\text{k}\Omega$ ,  $R_2 = 20\text{k}\Omega$  and  $R_4 = 21\text{k}\Omega$ . Determine  $V_0$  when  $V_1 = +1\text{V}$  and  $V_2 = -1\text{V}$  [10]